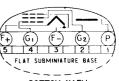


COATED FILAMENT 1.25 VOLTS 0.04 AMP. AC OR DC ANY MOUNTING POSITION



BOTTOM VIEW

O.016" TINNED FLEXIBLE LEADS 0.05" SPACING CENTER-TO-CENTER

GRID #3 IS COMPRISED OF TWO SEPARATE DEFLECTOR PLATES, ONE OF WHICH IS CONNECTED TO LEAD 3 AND THE OTHER TO LEAD 5.

GLASS BULB RED DOT IS ADJACENT TO LEAD 1

BULB IS ENTIRELY COATED WITH A METALLIC SHIELD CONNECTED TO LEAD 3.

THE 1AH4 IS A FILAMENT TYPE, FULLY SHIELDED, SUBMINIATURE PENTODE DESIGNED FOR SERVICE IN RF APPLICATIONS REQUIRING ECONOMY OF SPACE, WEIGHT, AND BATTERY DRAIN. THE FLEXIBLE TERMINAL LEADS MAY BE SOLDERED OR WELDED TO CIRCUIT COMPONENTS WITHOUT THE USE OF SOCKETS. STANDARD SUBMINIATURE SOCKETS MAY BE USED BY CUTTING THE LEADS TO 0.20" LENGTH.

## DIRECT INTERELECTRODE CAPACITANCES

GRID TO PLATE (MAX.)	0.01	μμ f
INPUT	3.5	<b>μ</b> μ f
OUTPUT	4.5	μμ f

## RATINGS

INTERPRETED ACCORDING TO RMA STANDARD M8-210

DESIGN CENTER VALUES

FILAMENT VOLTAGE	1.25	VOLTS
PLATE VOLTAGE	90	VOL TS
GRID #2 VOLTAGE	90	VOLTS
TOTAL CATHODE CURRENT	2.0	MA.

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## - TUNG·SOL --

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## TYPICAL OPERATING CONDITIONS AND CHARACTERISTICS

CLASS A1 AMPLIFIER

FILAMENT VOLTAGE	1.25	1.25	VOLTS
FILAMENT CURRENT	0.04	0.04	AMP.
PLATE VOLTAGE	45	67.5	VOLTS
GRID #2 VOLTAGE	45		VOL TS
GRID #2 SUPPLY VOLTAGE		67.5	VOL TS
GRID #2 RESISTOR		0.1	ME GOHM
GRID #1 RESISTOR <sup>A</sup>	0	0	VOLTS
PLATE RESISTANCE	1.5	2.0	ME GOHMS
TRANSCONDUCTANCE	750	750	<b>имн</b> оѕ
PLATE CURRENT	0.75	0.75	MA.
GRID #2 CURRENT	0.2	0.2	MA.
GRID #4 VOLTAGE (APPROX.) FOR TRANSCONDUCTANCE = 10 LIMHOS	-3	-3.5	VOLTS

 $<sup>^{\</sup>rm A}$  GRID RESISTOR = 5 MEGOHMS.